

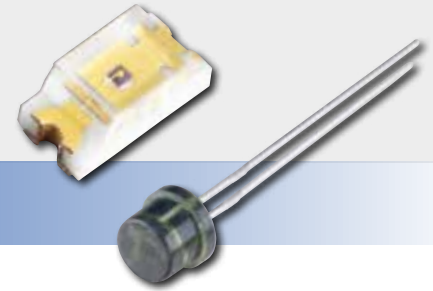
Application Specific Components

For Ambient Light Sensors & Radon Detection

PHOTODIODES & -TRANSISTORS FOR HIGH-VOLUME APPLICATIONS ■

Left: Spectrally Adapted Photodiodes and Phototransistors

Right: C30737PH Series T-1¾ (TO-like) Through-Hole Package (4.9 mm Diameter)



Spectrally Adapted Photodiodes and Phototransistors

Applications

- Interior and exterior light switching (dusk/dawn switch)
- Interior and exterior light control (dimming)
- Automotive headlight dimmer
- Display contrast control
- Energy conservation

Features and Benefits

- Response approaching human eye using Excelitas' IR-BLOC™ technology
- Perfect light sensor in conjunction with Excelitas' pyroelectric detectors for motion controlled light switches
- RoHS compliant
- Selectable wavelength detection range
- Small footprint
- Surface mount packages

Product Description

Ambient light sensors from Excelitas provide an easy solution for applications that require a response similar to the human eye, making it ideal when the response should only be influenced by visible light. These devices contribute in various applications to energy conservation in both fixed and portable devices. There are three main device types, one being filtered photodiodes, the second filtered phototransistors and finally wavelength selective devices based on III-V material. They are available in a number of standard packages, including surface mount for automated assembly.

Product Table

Spectrally Adapted Photodiodes and Phototransistors

| Symbol | Package | Active Area mm ² | Min. Short Circuit Current @ H = 100fc, 2850K | | Maximum Dark Current (nA) | Maximum Junction Capacitance (nF) | Typical Radio-metric Sensitivity @ λ _p | Spectral Range λ _{RANGE} nm | Typical Peak Wavelength λ _p nm | Typical Noise Equivalent Power (W/√Hz) |
|-------------|--------------|--------------------------------|---|------------------------------|------------------------------|-----------------------------------|---|--|---|---|
| | | | min I _{sc} μA | typ S _R A/W | | | | | | |
| VTP9812FH | T-1 3/4 flat | 1.548 | 0.7 | 10 @ V _R = 10V | 0.15 @ V _R = 10V | 0.034 | 400-700 | 580 | - | |
| VTB1012BH | TO-46 | 1.6 | 0.8 | 0.1 @ V _R = 2V | 0.31 @ V _R = 0V | 0.3 | 330-720 | 580 | 5.3 X 10 ⁻¹⁴ | |
| VTB1013BH | TO-46 | 1.6 | 0.8 | 0.02 @ V _R = 2V | 0.31 @ V _R = 0V | 0.3 | 330-720 | 580 | 1.1 X 10 ⁻¹⁴ | |
| VTB6061CIEH | TO-8 | 37.7 | - | 2 @ V _R = 2V | 11 @ V _R = 0V | - | 475-650 | 555 | 1.3 X 10 ⁻¹³ | |
| VTT9812FH | T-1 3/4 flat | 0.191 | 60 | 50 @ V _{CE} = 5V | - | 7 | 450-700 | 585 | - | |
| VTT9814FH | T-1 3/4 flat | 0.191 | 80 (min) 120 (max) | 50 @ V _{CE} = 5V | - | 7 | 450-700 | 585 | - | |

Electrical characteristics at T_{Ambient} = 25 °C

Product Description

The VTH21xx series photodiodes have a large active area and low capacitance and are specifically designed for alpha particle detection. They are available in bare chips to suit the alpha particle / radon detection, shipped in wafer pack. Custom packages are available as options.

Product Table

Large Area Photodiodes for Alpha Particle / Radon Detection

| Part Number | Package | Active Size (mm) | Active Area (mm) | Junction Capacitance | |
|-------------|-----------|---------------------|---------------------|-------------------------------|-----------------------------|
| | | | | Dark Current Typical (nA) | Typical (pF) |
| VTH2110 | Bare chip | 5 x 5 | 25 | 0.2 nA @ V _r = 50V | 20pF @ V _r = 50V |
| VTH2120 | Bare chip | 10 x 10 | 100 | 1 nA @ V _r = 50V | 80pF @ V _r = 50V |